

Data Sheet March 2001

30 A, 600 V, Ultrafast Diode

The RURP3060 is an ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURP3060	TO-220AC	RURP3060

NOTE: When ordering, use the entire part number.

Symbol



Features

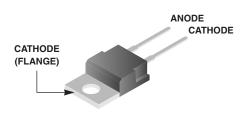
- Ultrafast Recovery t_{rr} = 60 ns (@ I_F = 30 A)
- Max Forward Voltage, V_F = 1.5 V (@ T_C = 25°C)
- 600 V Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- RoHS Compliant

Applications

- · Switching Power Supply
- · Power Switching Circuits
- General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

	RURP3060	UNIT
Peak Repetitive Reverse Voltage	600	V
Working Peak Reverse VoltageV _{RWM}	600	V
DC Blocking Voltage	600	V
Average Rectified Forward Current ($T_C = 130^{\circ}C$) $I_{F(AV)}$	30	Α
Repetitive Peak Surge Current	70	Α
Nonrepetitive Peak Surge Current	325	Α
Maximum Power Dissipation	125	W
Avalanche Energy (See Figures 7 and 8)	20	mJ
Operating and Storage Temperature	-55 to 175	°C

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
V _F	F I _F = 30 A		-	1.5	V
	$I_F = 30 \text{ A}, T_C = 150^{\circ}\text{C}$	-	-	1.3	V
I _R	V _R = 600 V	-	-	250	μА
	$V_R = 600 \text{ V}, T_C = 150^{\circ}\text{C}$	-	-	1	mA
t _{rr}	I _F = 1A , dI _F /dt = 100 A/μs	-	-	55	ns
	I _F = 30 A, dI _F /dt = 100 A/μs	-	-	60	ns
ta	I _F = 30 A, dI _F /dt = 100 A/μs	-	30	-	ns
t _b	I _F = 30 A, dI _F /dt = 100 A/μs	-	20	-	ns
$R_{ heta JC}$		-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 T_{rr} = Reverse recovery time at dI_F/dt = 100A/ μs (See Figure 6), summation of t_a + t_b .

 t_a = Time to reach peak reverse current at dI_F/dt = 100A/ μ s (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

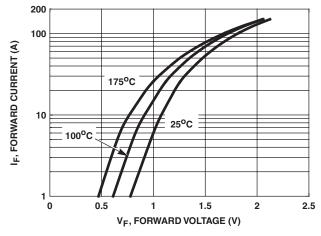


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

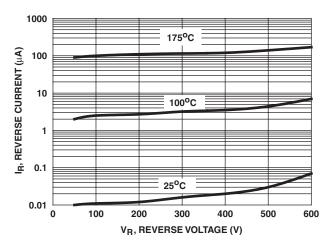


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

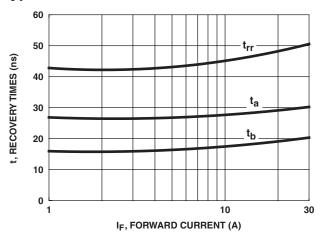


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

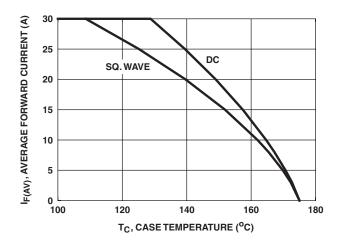


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

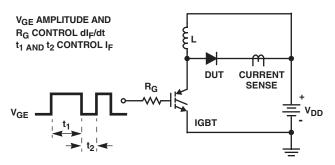


FIGURE 5. t_{rr} TEST CIRCUIT

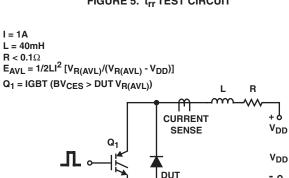


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

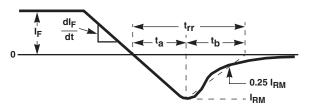


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

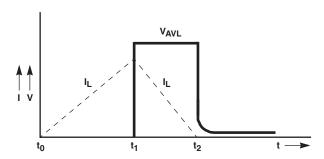


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



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Definition of Terms

Definition of Terms				
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